Experimental estimates of in-plane thermal conductivity in FePt-C granular thin film heat assisted magnetic recording media using a model layered system

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Cross-plane thermal conductivity $k_{th}$ measurements of vertical stacks of FePt/C were used to estimate the in-plane thermal conductivity of Heat Assisted Magnetic Recording (HAMR) media that consist of columnar FePt grains segregated by thin C grain boundaries. FePt/C multilayers with varied repeat units and FePt layer thicknesses (chosen to represent HAMR media grain sizes) were measured using Frequency-Domain Thermoreflectance to determine $k_{th}$ in the direction normal to the layers. The data suggest that when FePt grains are less than 8 nm in diameter, the in-plane $k_{th}$ for HAMR media is below 1 W/m-K and the anisotropy of $k_{th}$ (cross-plane/in-plane) will exceed 10.

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Heat Assisted Magnetic Recording (HAMR) is a leading candidate for the next generation hard disk drive.1–4 The main technological difference between HAMR and conventional perpendicular magnetic recording (PMR) lies in the writing process, which involves local heating to beyond the Curie temperature $T_C$ using light, followed by rapid cooling in the presence of the applied head field to switch the magnetization. HAMR can solve the technology trilemma that PMR is now facing.5 With high magnetocrystalline anisotropy $L_{100}$ FePt, media overcome the super-paramagnetic limit, while local heating to reduce the anisotropy field during the writing process overcomes the write field limitations. The effective write field gradient, which must be high to minimize medium noise, is contributed by the gradient of the anisotropy field versus temperature near $T_C$ of FePt, and the spatial gradient of temperature in the vicinity of the heat spot.6 Hence, understanding the thermal conductivity of FePt thin films is central to obtaining the proper thermal profile during writing.6–8

FePt magnetic media are typically sputtered with amorphous segregant such as C9–11 to produce small and isolated grains. Plan-view and cross-sectional Transmission Electron Microscope (TEM) images of FePt granular media with about 15 nm grain size are shown in Fig. 1(a). In this granular structure, the in-plane thermal conductivity is expected to be smaller than the cross-plane thermal conductivity because phonons and electrons that carry heat are scattered at the segregant interfaces between FePt grains12 as illustrated in Figure 1(b). Fernandez et al.13 investigated the overall cross-plane thermal resistance of layered magnetic structures including FePt films on underlayers and heat sink layers. Measurement of in-plane thermal conductivity, on the other hand, is extremely challenging, when it is low, as it is in these films, because cross-plane thermal conduction paths into the underlayers or substrate dominate the measurement.14,15 In this paper, we present an experimental approach that allows us to estimate the in-plane thermal conductivity in FePt granular thin films, by making a measurement on an experimental model system that avoids parallel thermal conduction pathways.

The model system consists of FePt and C multilayer stacks whose vertical heat conduction gives insight into the lateral thermal conduction in a real granular medium layer. The thermal conductivities of the film stacks in the direction normal to the layers were characterized using the Frequency-Domain Thermoreflectance (FDTR) technique16–19 as illustrated in Figure 1(c), and we take those to be representative of the in-plane thermal conductivity of granular films when the lateral grain size is similar to the FePt thickness in the model samples. To estimate the effect of media grain size on the in-plane lateral thermal conduction, the thickness of FePt layer was varied from 14.5 nm to 29 nm. The C layer thickness, which represents grain boundary thickness, was fixed at 1 nm.

The film stacks were fabricated by RF sputtering from Fe52.5Pt47.5 and C targets at a base pressure of better than $2 \times 10^{-7}$ Torr. To measure the thermal conductivity of the stack, the multilayer FePt/C film was deposited onto a 1 in. phosphorous-doped Si wafer and capped by a sputtered Au layer (43 nm) with a thin Ti adhesion layer (2 nm). The Si wafer was cleaned with buffered HF to remove the native oxide layer before entering the vacuum chamber. The Au top layer both absorbs light and acts as a reflectance-based thermometer for the FDTR measurements. FePt and C layers were deposited at an Ar pressure of 25 mTorr, room temperature, and a power of 50 W and 150 W, respectively.20 Two sets of samples with varying number of FePt/C repeated units and different FePt layer thicknesses were made:

(1) Si/[FePt_{14.5 nm}/C_{1nm}]/FePt_{14.5 nm}/Au (N = 1, 2, 3, 5, and 10) which are notated as 1N1, 1N2, 1N3, 1N5, and 1N10 and (2) Si/[FePt_{29nm}/C_{1nm}]/FePt_{29nm}/Au (N = 1, 5, and 10) which are notated as 2N1, 2N5, and 2N10. The cross-sectional TEM images in Figures 2(d)–2(f) show that the periodic structures of 1N3, 1N10, and 2N10 have well-defined FePt and C layers.

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In the FDTR method\textsuperscript{16,18,19} schematically illustrated in Figure 2(a), two continuous wave lasers periodically heat the sample and measure its thermal response to determine the unknown thermal transport properties of the FePt/C stack. The 1/e\textsuperscript{2} effective radius of the Gaussian laser spots on the sample surface was measured by knife-edge to be 2.6 ± 0.2 \( \mu m \). The pump laser (488 nm) was intensity modulated by an electro-optic modulator and heated the Au top layer over a range of frequencies from 100 kHz to 20 MHz. The periodic temperature change of the sample was continuously monitored by the probe laser (532 nm) through the temperature dependent reflectivity of the Au surface. The resultant probe signal measured by a photodiode was analyzed using an RF lock-in amplifier to generate frequency-dependent phase lag of temperature change relative to the heat flux. The unknown thermal conductivity of materials of interest was then obtained by fitting these phase data to an analytical solution of the diffusive heat conduction equation.\textsuperscript{21} The unknown fitting parameters were the effective thermal conductivity of the FePt/C stack and Si substrates. As input to the fitting program, the layer thicknesses were measured from the cross section TEM images. Likewise, the \( k_{th} \) values of Au were calculated from the Au sheet resistance as measured by 4-point probe measurements for separate Au films deposited on 1 \( \mu m \)-thick thermally grown SiO\textsubscript{2} films on Si substrates following the Weidemann Franz Law. The \( k_{th} \) value of n-type Si substrates were found to be 95 ± 10 W/m-K, which appears low relative to the bulk value (143 W/m-K) for Si, but is reasonably attributed to the known suppression in \( k_{th} \) observed by high frequency FDTR measurements\textsuperscript{17,18} paired with effects of added phonon scattering due to phosphorous dopant concentration of about 10\textsuperscript{15} cm\textsuperscript{-3} (Ref. 22).

The mass density, \( \rho \), values of FePt/C film stacks were an average of mass density of Fe\textsubscript{52.5}Pt\textsubscript{47.5} (15028 kg/m\textsuperscript{3}) (Refs. 23

\begin{figure}[h]
\centering
\includegraphics[width=\linewidth]{figure1}
\caption{(a) Plan-view and cross-sectional TEM images of FePt granular media; (b) Schematic of heat conduction in granular media; (c) Structure of FePt/C model system (the laser beams are not drawn to scale); and cross-section TEM images of (d) 1N3, (e) 1N10, and (f) 2N10.}
\end{figure}

\begin{figure}[h]
\centering
\includegraphics[width=\linewidth]{figure2}
\caption{(a) Schematic illustration of FDTR set up, (b) Phase data and fitting curves of 1N3 and 1N10 against the modulation frequency.}
\end{figure}
and 24) and amorphous C (1950 kg/m$^3$) (Ref. 25) by thickness percentage. The heat capacity values, $C_p$, of the FePt/C film stacks were taken to be an average of the mass heat capacity of Fe$_{52.5}$Pt$_{47.5}$ (207 J/kg-K) (Ref. 23 and 24) and amorphous C (450 J/kg-K) (Ref. 26) by weight percentage.

Figure 2(b) is two sets of phase lag data of the temperature change in the Au layer as a function of laser-intensity-modulation frequency for samples 1N3 and 1N10. Best fitting curves give the $k_{th}$ and thicknesses $L$ of the [FePt/C]$_N$/FePt film stacks are listed in Table I. These values were averaged over 3 measurements at 3 locations on the samples. The reported uncertainty was estimated following the uncertainty analysis described elsewhere$^{16}$ assuming ±2% uncertainties in the value of $\rho$, $C_p$, and thickness of the Au layer, [FePt/C]$_N$/FePt stack and Si substrate; ±5% uncertainty in the $k_{th}$ of the Au layer; and ±10% in the $k_{th}$ of the Si substrate and laser spot size. The resulting thermal conductivities have uncertainties of 4%–12%. The thermal conductivity extracted from the fit includes the interfacial thermal conductance of Au and Si as part of the bulk layered stack. To separate out these interface contributions, the thermal resistance of the samples, $R_{th} = L/k_{th}$, was plotted versus the number of FePt/C repeat units $N$ for two sets of FePt layer thicknesses (14.5 nm and 29 nm). The total thermal resistance can be simply written as

$$R_{th} = N(m R_{FePt} + R_C + 2 R_I + R_{In-Au} + R_{In-Si} + m R_{FePt},)$$

where $N = 1, 2, 3, 5,$ and 10; $m = 1, 2,$ and $R_{FePt}$, $R_C$, $R_I$, $R_{In-Au}$, and $R_{In-Si}$ are the thermal resistances of 14.5 nm thick FePt layer, 1 nm thick C layer, interface between FePt and C layers, interface between FePt and Au layers, and interface between FePt layers and Si substrates, respectively. As seen in Figure 3, the total thermal resistance is linearly dependent on the number of repeats $N$ for both two sets of stack samples. The slope gives us the thermal resistance of the FePt/C unit. When converted to thermal conductivity values, these values give $k_{th}$ of 1.8 ± 0.2 W/m-K and 3.0 ± 0.4 W/m-K for FePt$_{14.5}$nm/C$_{1}$nm and FePt$_{29}$nm/C$_{1}$nm, respectively. The thermal resistance of 14.5 nm FePt layer ($R_{FePt}$) and the collective thermal resistance of the carbon layer and its associated interfaces ($R_C$ + 2$R_I$) can be obtained by solving the unknowns from the two slope values. $R_{FePt}$ is equal to 1.7 ± 1.5 K-m$^2$/GW and ($R_C$ + 2$R_I$) is equal to 6.7 ± 2.2 K-m$^2$/GW. Dividing the FePt layer thickness (14.5 nm) and C layer thickness (1 nm) by their corresponding thermal resistance, the thermal conductivity $k_{th}$ of FePt layer is therefore 8.5 ± 7.5 W/m-K and that of amorphous C layer is 0.15 ± 0.05 W/m-K.

The C interlayer has a much smaller $k_{th}$ than the FePt layer. Our measured value of the C layer is consistent with prior measurements of amorphous C films which range from 0.2–2.2 W/m-K, depending on its mass density.$^{27}$ Heat conduction across the FePt/C interface is likely dominated by phonons since C is non-metallic. The two C/FePt thermal boundary resistances ($2R_I$) are grouped into this value, resulting in an even lower $k_{th}$ for C. Due to the low thermal resistance of FePt, as compared to C in the film stack, the measurement becomes insensitive to the thermal conductivity of FePt, leading to significant uncertainty. The impedance of the FePt/C stack samples mostly stems from the amorphous C layer and its boundaries. That explains a decrease in thermal conductivity of FePt/C from 3.0 ± 0.4 W/m-K to 1.8 ± 0.2 W/m-K when FePt layer thickness is reduced from 29 nm to 14.5 nm. It also implies that FePt-C granular media with smaller grain size will have lower lateral thermal conductivity in the film plane due to the presence of more FePt/C interfaces per unit length. From our results, the cross-plane thermal conductivity of FePt is 4.6 ± 4.1 times higher than the in-plane thermal conductivity of FePt-C granular system of 14.5 nm grain size. We speculate that the cross-plane conductivity of FePt-C could be as high as that of FePt. For media in the tetrabit/in$^2$ regime, the FePt grain size will be even smaller than 8 nm. Under these circumstances, heat conduction in the FePt-C granular media would be even more anisotropic, with an anisotropy higher than 10, based on our results. From the standpoint of media design, this anisotropic nature of heat conduction minimizes the lateral spreading of the temperature profile during the writing process.

![Graph](image-url)  

**FIG. 3.** Total thermal resistance $R_{th}$ versus number of repeat units $N$ for two sets of samples. The linear lines are the weighted least square fitting.

<table>
<thead>
<tr>
<th>Sample</th>
<th>Stack thickness $L$ (nm)</th>
<th>Effective thermal conductivity $k_{th}$ (W/m-K)</th>
</tr>
</thead>
<tbody>
<tr>
<td>1N1</td>
<td>30</td>
<td>0.92 ± 0.05</td>
</tr>
<tr>
<td>1N2</td>
<td>45.5</td>
<td>1.10 ± 0.08</td>
</tr>
<tr>
<td>1N3</td>
<td>61</td>
<td>1.32 ± 0.10</td>
</tr>
<tr>
<td>1N5</td>
<td>92</td>
<td>1.35 ± 0.10</td>
</tr>
<tr>
<td>1N10</td>
<td>169.5</td>
<td>1.56 ± 0.16</td>
</tr>
<tr>
<td>2N1</td>
<td>59</td>
<td>1.89 ± 0.09</td>
</tr>
<tr>
<td>2N5</td>
<td>179</td>
<td>2.4 ± 0.2</td>
</tr>
<tr>
<td>2N10</td>
<td>329</td>
<td>2.8 ± 0.3</td>
</tr>
</tbody>
</table>

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down-track directions offers a sharp switching field that ben-
efits signal-to-noise ratio.

We note that the FePt layers in our sample are in the dis-
ordered FCC state, even though in real HAMR media FePt
must be a very well ordered L10 structure to harness its high
magnetocrystalline anisotropy.28 The $k_{th}$ of the L10 state is
expected to be moderately larger than that of the disordered
FCC state.29 Since the C boundaries are found to be the pre-
dominant thermal resistance, our results for disordered FePt
thin films should still be generally applicable to the L10 or-
dered case.

In summary, we have developed a model experimental
system to quantitatively determine the lateral thermal con-
duction in the FePt-C granular media for HAMR applica-
tions. The thermal boundary resistance of C is shown to be
dominant in the in-plane thermal resistance of the media,
which will lead to an increase in thermal resistance as
smaller grain media are realized. It has been found that heat
conduction in FePt-C granular media with 14.5 nm grain size
exhibits anisotropic thermal conductivity by a factor of
4.6 ± 4.1 compared to along a lateral direction. This exper-
imental model can be employed to further study the effect of
segregant material choices and grain boundary thicknesses
on lateral heat conduction in HAMR media.

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